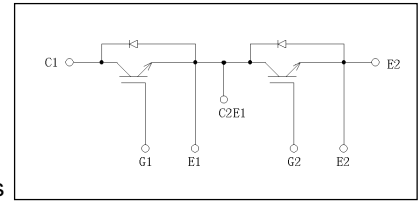


2MBI150U2A-060

IGBT Module U-Series 600V / 150A 2 in one-package

Equivalent Circuit Schematic



Features

- High speed switching
- Voltage drive
- Low inductance module structure

Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines

Maximum ratings and characteristics

Absolute maximum ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Conditions	Rating	Unit	
Collector-Emitter voltage	V_{CES}		600	V	
Gate-Emitter voltage	V_{GES}		± 20	V	
Collector current	I_c	Continuous	150	A	
	I_{cp}	1ms	300		
	$-I_c$		150		
	$-I_c$ pulse		300		
Collector Power Dissipation	P_c	1 device	500	W	
Junction temperature	T_j		+150	$^\circ\text{C}$	
Storage temperature	T_{stg}		-40 to +125		
Isolation voltage	between terminal and copper base *1	V_{iso}	AC:1min.	2500	VAC
Screw Torque	Mounting *2			3.5	N·m
	Terminals *2			3.5	

*1 : All terminals should be connected together when isolation test will be done.

*2 : Recommendable value : Mounting 2.5 to 3.5N·m(M5 or M5), Terminal 2.5 to 3.5 N·m(M5)

Electrical characteristics (at $T_j=25^\circ\text{C}$ unless otherwise specified)

Item	Symbols	Conditions	Characteristics			Unit	
			Min.	Typ.	Max.		
Zero gate voltage collector current	I_{CES}	$V_{GE}=0\text{V}$, $V_{CE}=600\text{V}$	–	–	1.0	mA	
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0\text{V}$, $V_{GE}=\pm 20\text{V}$	–	–	200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE}=20\text{V}$, $I_c=150\text{mA}$	6.2	6.7	7.7	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE}=15\text{V}$, $I_c=150\text{A}$	$T_j=25^\circ\text{C}$	–	2.05	2.35	V
			$T_j=125^\circ\text{C}$	–	2.30	–	
	$V_{CE(sat)}$ (chip)		$T_j=25^\circ\text{C}$	–	1.80	–	
			$T_j=125^\circ\text{C}$	–	2.05	–	
Input capacitance	C_{ies}	$V_{CE}=10\text{V}$, $V_{GE}=0\text{V}$, $f=1\text{MHz}$	–	12	–	nF	
Turn-on time	t_{on}	$V_{CC}=300\text{V}$	–	0.40	1.20	μs	
	t_r	$I_c=150\text{A}$	–	0.22	0.60		
	$t_{r(i)}$	$V_{GE}=\pm 15\text{V}$	–	0.16	–		
Turn-off time	t_{off}	$R_G=24\ \Omega$	–	0.48	1.20	μs	
	t_f		–	0.07	0.45		
Forward on voltage	V_F (terminal)	$V_{GE}=0\text{V}$ $I_F=150\text{A}$	$T_j=25^\circ\text{C}$	–	1.80	2.20	V
			$T_j=125^\circ\text{C}$	–	1.85	–	
	V_F (chip)		$T_j=25^\circ\text{C}$	–	1.60	–	
			$T_j=125^\circ\text{C}$	–	1.65	–	
Reverse recovery time	t_{rr}	$I_F=150\text{A}$	–	–	0.35	μs	
Lead resistance, terminal-chip*3	R lead		–	1.39	–	m Ω	

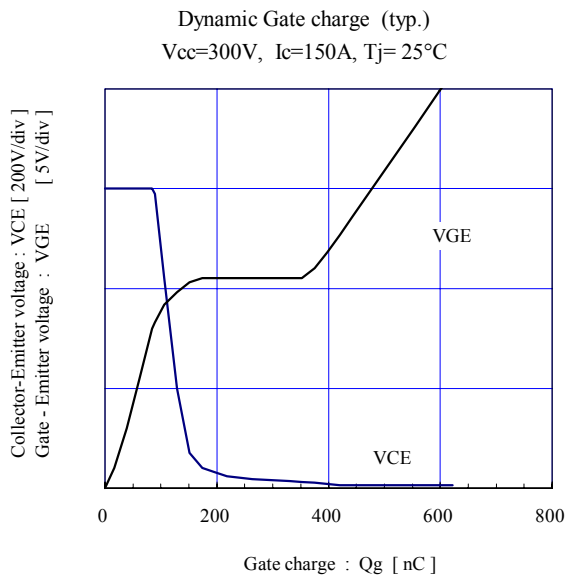
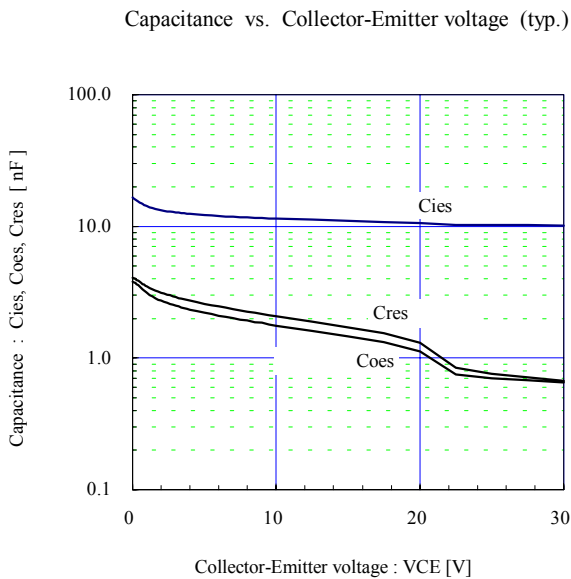
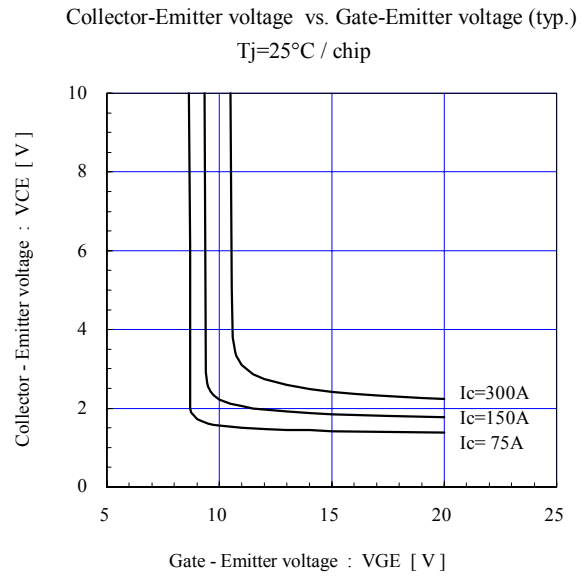
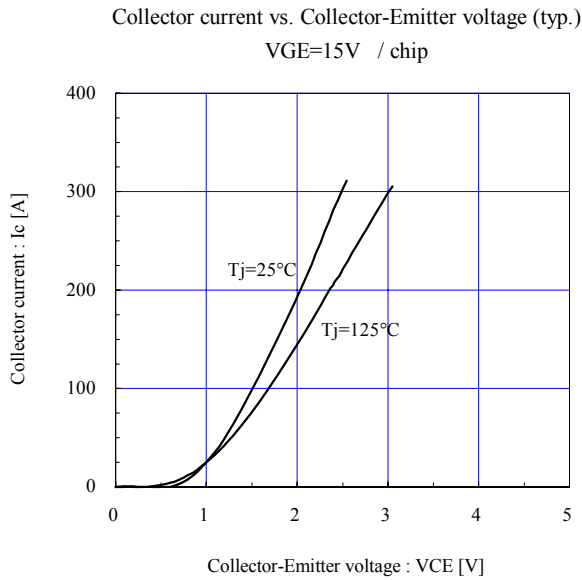
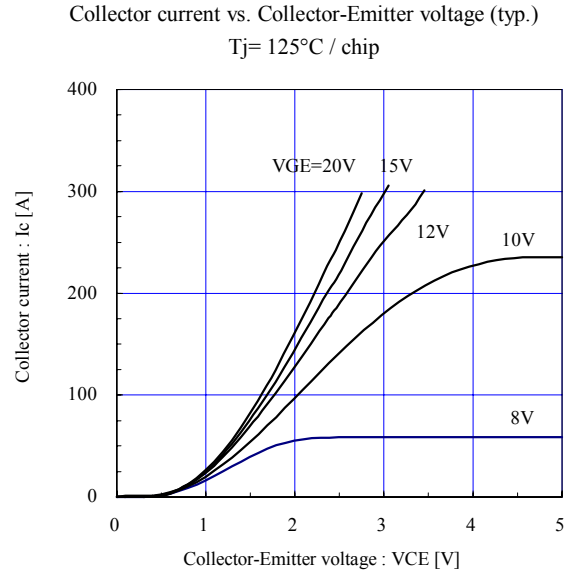
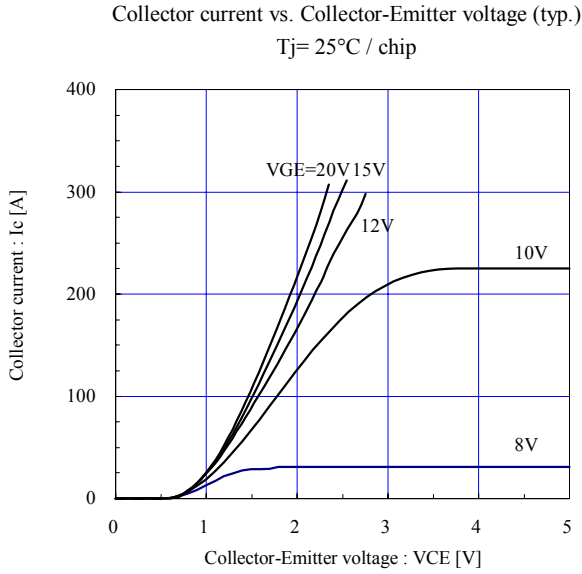
*3:Biggest internal terminal resistance among arm.

Thermal resistance characteristics

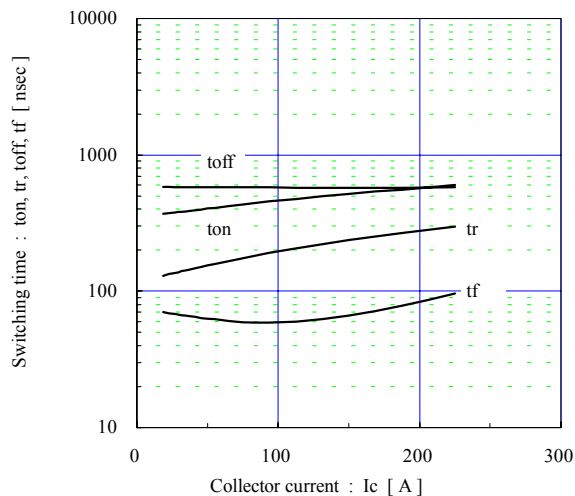
Items	Symbols	Conditions	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	IGBT	–	–	0.25	$^\circ\text{C/W}$
	$R_{th(j-c)}$	FWD	–	–	0.46	$^\circ\text{C/W}$
Contact Thermal resistance	$R_{th(c-f)}$ *4	With thermal compound	–	0.05	–	$^\circ\text{C/W}$

*4 : This is the value which is defined mounting on the additional cooling fin with thermal compound.

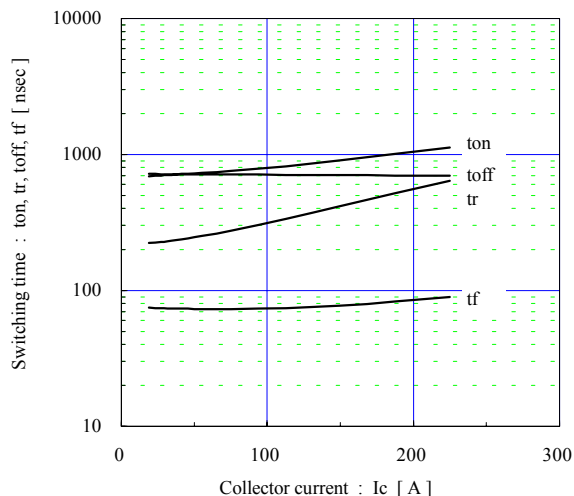
Characteristics (Representative)



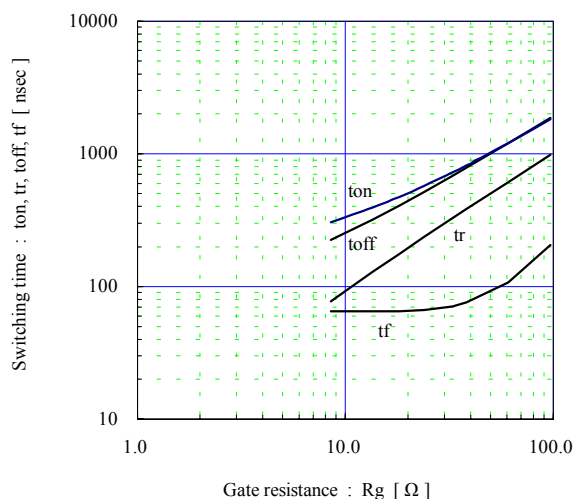
Switching time vs. Collector current (typ.)
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=24\Omega, T_j=25^\circ C$



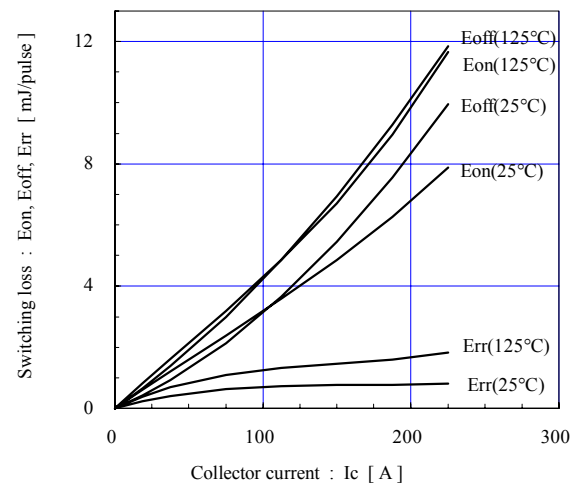
Switching time vs. Collector current (typ.)
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=24\Omega, T_j=125^\circ C$



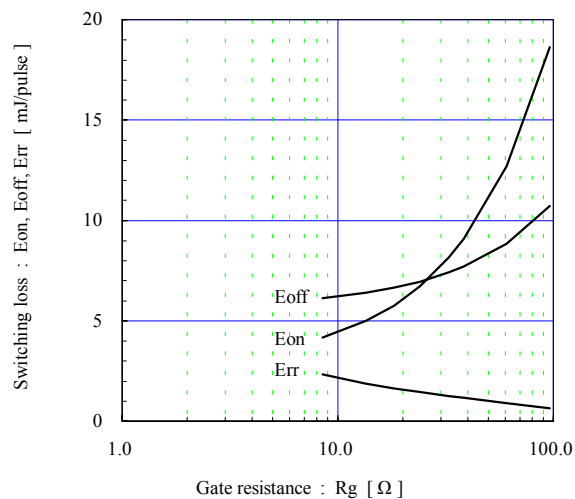
Switching time vs. Gate resistance (typ.)
 $V_{cc}=300V, I_c=150A, V_{GE}=\pm 15V, T_j=25^\circ C$



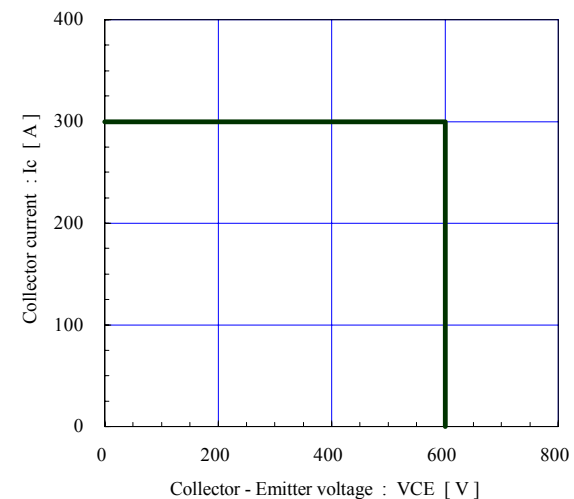
Switching loss vs. Collector current (typ.)
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=24\Omega$



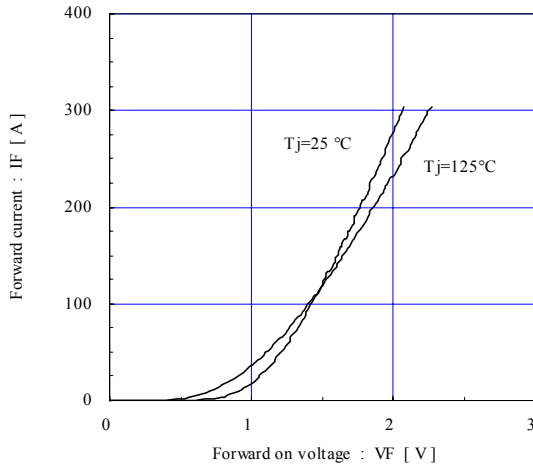
Switching loss vs. Gate resistance (typ.)
 $V_{cc}=300V, I_c=150A, V_{GE}=\pm 15V, T_j=125^\circ C$



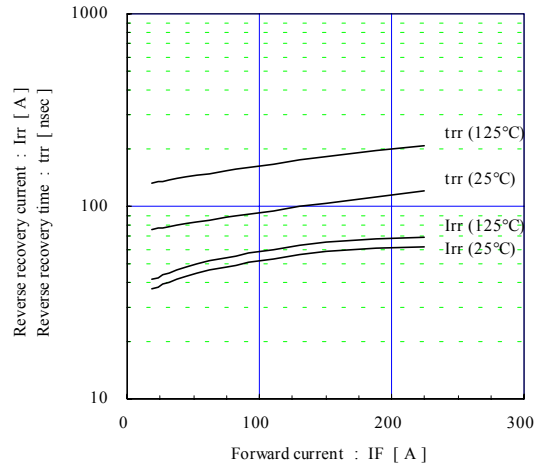
Reverse bias safe operating area (max.)
 $+V_{GE}=15V, -V_{GE} \le 15V, R_g \ge 24\Omega, T_j \le 125^\circ C$



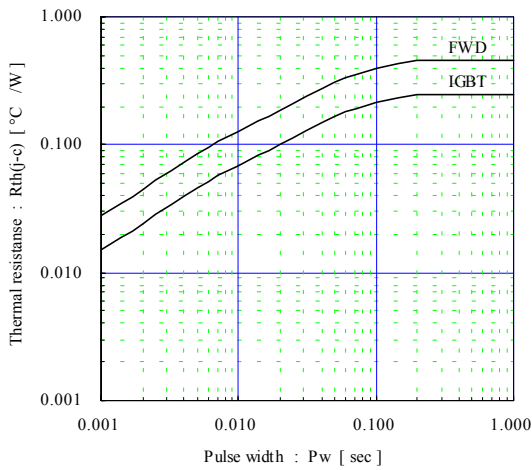
Forward current vs. Forward on voltage (typ.)
chip



Reverse recovery characteristics (typ.)
 $V_{cc}=300\text{V}$, $V_{GE}=\pm 15\text{V}$, $R_g=24\Omega$



Transient thermal resistance (max.)



■ Outline Drawings, mm

M232

